NSN 5961-01-338-3618

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-338-3618 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.762 inches **Overall Width:** 1.050 inches **Function For Which Designed:** Rectifier **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 45.0 repetitive peak reverse voltage all semiconductor device diode and 35.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 30.00 amperes forward current, average absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No